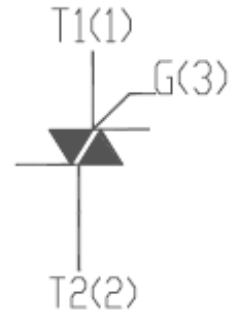


● Features:

- * NPNPN Bi-direction Triac
- * Back multilayer metal electrode
- * High temperature reliability
- * Glass Passivated junction chips

Application:

Power tool ,moto speed controller,Vacuum cleaner,heating temperature controller, Solid state relay and phase control circuits.



● Limiting Values

Symbol	Absolute maximum ratings Parameters		Value	Unit
$I_{T(RMS)}$	RMS on-state current	$T_c=80^{\circ}C$	6	A
I_{TSM}	Non repetitive surge peak on-state current	$F=50HZ$ $t=20ms$	60	A
I^2t	I^2t value for fusing	$t_p=10ms$	18	A^2S
di/dt	Critical rate of rise of on-state current	$T_j=125^{\circ}C$	50	A/us
V_{DRM}/V_{RRM}	Non repetitive surge peak off-state voltage	$T_j=25^{\circ}C$	600	V
I_{GM}	Peak gate current	$t_p=20us$ $T_j=125^{\circ}C$	4	A
$P_{G(AV)}$	Average gate power dissipation	$T_j=125^{\circ}C$	1	W
T_{stg}	Storage junction temperature range		-40~ +150	°C
T_j	Operating junction temperature range		-40~ +125	

● Electrical Characteristics(Ta=25°C unless otherwise specified)

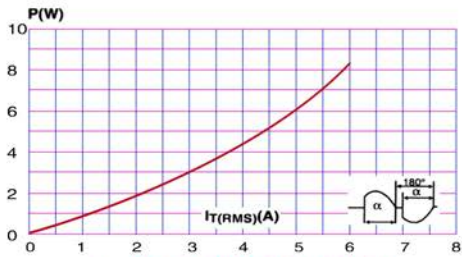
Symbol	Test Conditions	Quadrant		Value	Unit	
I_{GT}	$V_D=12V R_L=100\Omega$	I II III IV	MAX	I II III	IV	mA
				$\cong 25$	$\cong 50$	
V_{GT}	Tj=125°C		MAX	1.5		V
V_{GD}			MIN	0.2		V
I_H	$I_T=0.5A$		MAX	60		mA
I_L	$I_G=1.2I_{GT}$	MAX	I -III	60	mA	
			II	100		
dv/dt	$V_D=2/3V_{DRM} T_j=125^\circ C$		MIN	500		V/us
(dv/dt)c	Tj=125°C		MIN	10		V/us

● Static Characteristics

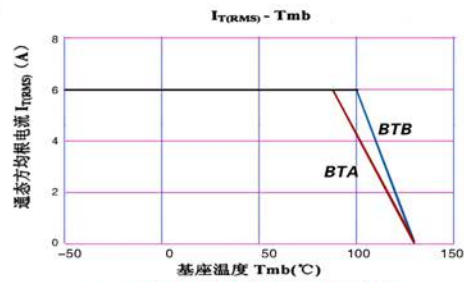
Symbol	Test Conditions		Value	Unit
V_{TM}	$I_{TM}= 32A T_j=25^\circ C$	MAX	1.45	V
V_{T0}	Tj=125°C	MAX	0.86	V
Rd	Tj=125°C	MAX	36.6	mΩ
I_{DRM} I_{RRM}	Tj=25°C	MAX	5	uA
	Tj=125°C		1	mA
$R_{th(j-c)}$	BTA		2.05	°C/W

● Typical Characteristics

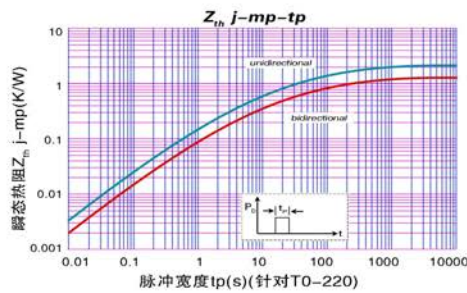
BTA06,BTB06特性曲线(T0-220)



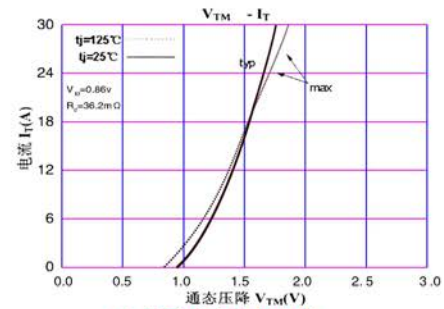
1、功耗与电流曲线 (180°)



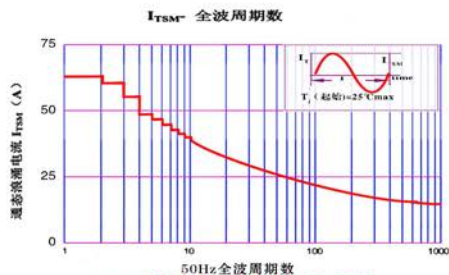
2、壳温与通态方均根电流曲线



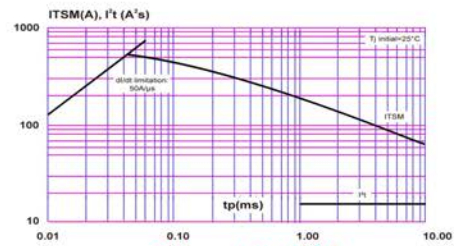
3、瞬态热阻曲线



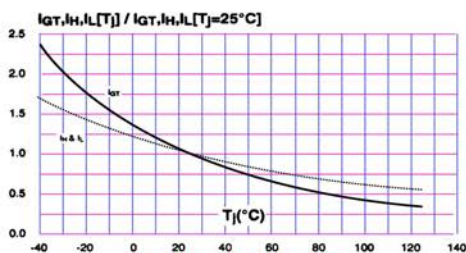
4、通态伏安特性曲线



5、浪涌电流与周波数曲线



6、 $I_{TSM}-t, I^2t-t$ 曲线



7、门极触发特性曲线

● TO-220 Outline Package Dimension

Unit: mm (± 0.1)

